NSN 5961-01-068-4141

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View Online at https://aerobasegroup.com/nsn/5961-01-068-4141 **Inclosure Material:** Plastic **Overall Length:** Between 0.560 inches and 0.625 inches **Overall Height:** Between 0.140 inches and 0.190 inches Overall Width: Between 0.380 inches and 0.420 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method:** Bracket and unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 collector to base voltage/static/emitter open and 90.0 collector to emitter reverse voltage and 90.0 collector to emitter voltage, dc with specified circuit between base and emitter and 80.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 15.00 amperes source cutoff current **Power Rating Per Characteristic:** 75.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: